

3.3V ECL 1:2 Differential Fanout Buffer

The MC100LVEL11 is a differential 1:2 fanout buffer. The device is functionally similar to the E111 device but with higher performance capabilities. Having within-device skews and output transition times significantly improved over the E111, the LVEL11 is ideally suited for those applications which require the ultimate in AC performance.

The differential inputs of the LVEL11 employ clamping circuitry to maintain stability under open input conditions. If the inputs are left open (pulled to V_{FF}) the Q outputs will go LOW.

- 330 ps Propagation Delay
- 5 ps Skew Between Outputs
- High Bandwidth Output Transitions
- The 100 Series Contains Temperature Compensation
- PECL Mode Operating Range: $V_{CC} = 3.0\text{ V}$ to 3.8 V with $V_{EE} = 0\text{ V}$
- NECL Mode Operating Range: $V_{CC} = 0\text{ V}$ with $V_{EE} = -3.0\text{ V}$ to -3.8 V
- Internal Input Pulldown Resistors
- Q Output will Default LOW with Inputs Open or at V_{EE}

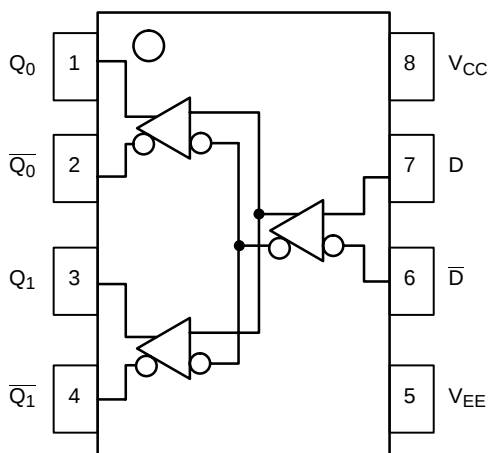


Figure 1. Logic Diagram and Pinout Assignment

PIN DESCRIPTION

PIN	FUNCTION
Q0, $\overline{Q0}$; Q1, $\overline{Q1}$	ECL Data Outputs
D, $\overline{D}$	ECL Data Inputs
V _{CC}	Positive Supply
V _{EE}	Negative Supply



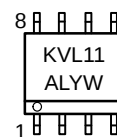
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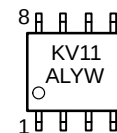
MARKING DIAGRAMS*



SO-8
D SUFFIX
CASE 751



TSSOP-8
DT SUFFIX
CASE 948R



A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week

*For additional marking information, see Application Note AND8002/D.

ORDERING INFORMATION

Device	Package	Shipping**
MC100LVEL11D	SO-8	98 Units / Rail
MC100LVEL11DR2	SO-8	2500 / Reel
MC100LVEL11DT	TSSOP-8	98 Units / Rail
MC100LVEL11DTR2	TSSOP-8	2500 / Reel

****For additional tape and reel information, see Brochure BRD8011/D.**

MC100LVEL11

ATTRIBUTES

Characteristics	Value
Internal Input Pulldown Resistor	75 k Ω
Internal Input Pullup Resistor	75 k Ω
ESD Protection	Human Body Model Machine Model Charge Device Model
	> 4 kV > 400 V > 2 kV
Moisture Sensitivity, Indefinite Time Out of Drypack (Note 1)	Level 1
Flammability Rating	Oxygen Index: 28 to 34
	UL 94 V-0 @ 0.125 in
Transistor Count	63
Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test	

1. For additional information, see Application Note AND8003/D.

MAXIMUM RATINGS (Note 2)

Symbol	Parameter	Condition 1	Condition 2	Rating	Units
V _{CC}	PECL Mode Power Supply	V _{EE} = 0 V		8 to 0	V
V _{EE}	NECL Mode Power Supply	V _{CC} = 0 V		-8 to 0	V
V _I	PECL Mode Input Voltage NECL Mode Input Voltage	V _{EE} = 0 V V _{CC} = 0 V	V _I ≤ V _{CC} V _I ≥ V _{EE}	6 to 0 -6 to 0	V
I _{out}	Output Current	Continuous Surge		50 100	mA mA
T _A	Operating Temperature Range			-40 to +85	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
θ _{JA}	Thermal Resistance (Junction-to-Ambient)	0 LFPM 500 LFPM	8 SOIC 8 SOIC	190 130	°C/W °C/W
θ _{JC}	Thermal Resistance (Junction-to-Case)	Standard Board	8 SOIC	41 to 44 ± 5%	°C/W
θ _{JA}	Thermal Resistance (Junction-to-Ambient)	0 LFPM 500 LFPM	8 TSSOP 8 TSSOP	185 140	°C/W °C/W
θ _{JC}	Thermal Resistance (Junction-to-Case)	Standard Board	8 TSSOP	41 to 44 ± 5%	°C/W
T _{sol}	Wave Solder	<2 to 3 sec @ 248°C		265	°C

2. Maximum Ratings are those values beyond which device damage may occur.

MC100LEVEL11

LVPECL DC CHARACTERISTICS $V_{CC} = 3.3\text{ V}$; $V_{EE} = 0.0\text{ V}$ (Note 3)

Symbol	Characteristic	-40 °C			25 °C			85 °C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I_{EE}	Power Supply Current		24	28		24	28		25	30	mA
V_{OH}	Output HIGH Voltage (Note 4)	2215	2295	2420	2275	2345	2420	2275	2345	2420	mV
V_{OL}	Output LOW Voltage (Note 4)	1470	1605	1745	1490	1595	1680	1490	1595	1680	mV
V_{IH}	Input HIGH Voltage (Single-Ended)	2135		2420	2135		2420	2135		2420	mV
V_{IL}	Input LOW Voltage (Single-Ended)	1490		1825	1490		1825	1490		1825	mV
V_{IHCMR}	Input HIGH Voltage Common Mode Range (Differential) (Note 8) $V_{pp} < 500\text{ mV}$ $V_{pp} \geq 500\text{ mV}$	1.2		3.1	1.1		3.1	1.1		3.1	V
		1.4		3.1	1.3		3.1	1.3		3.1	V
I_{IH}	Input HIGH Current			150			150			150	μA
I_{IL}	Input LOW Current	0.5			0.5			0.5			μA
		$\bar{D}$ -600			-600			-600			μA

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfm is maintained.

3. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary $\pm 0.3\text{ V}$.

4. Outputs are terminated through a $50\ \Omega$ resistor to $V_{CC} - 2\text{ V}$.

5. V_{IHCMR} min varies 1:1 with V_{EE} , max varies 1:1 with V_{CC} . The V_{IHCMR} range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between V_{ppmin} and 1 V .

LVNECL DC CHARACTERISTICS $V_{CC} = 0.0\text{ V}$; $V_{EE} = -3.3\text{ V}$ (Note 6)

Symbol	Characteristic	-40 °C			25 °C			85 °C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I_{EE}	Power Supply Current		24	28		24	28		25	30	mA
V_{OH}	Output HIGH Voltage (Note 7)	-108 5	-100 5	-880	-102 5	-955	-880	-102 5	-955	-880	mV
V_{OL}	Output LOW Voltage (Note 7)	-183 0	-169 5	-155 5	-181 0	-170 5	-162 0	-181 0	-170 5	-162 0	mV
V_{IH}	Input HIGH Voltage (Single-Ended)	-1 165		-880	-1 165		-880	-1 165		-880	mV
V_{IL}	Input LOW Voltage (Single-Ended)	-181 0		-147 5	-181 0		-147 5	-181 0		-147 5	mV
V_{IHCMR}	Input HIGH Voltage Common Mode Range (Differential) (Note 8) $V_{pp} < 500\text{ mV}$ $V_{pp} \geq 500\text{ mV}$	-2.1		-0.2	-2.2		-0.2	-2.2		-0.2	V
		-1.9		-0.2	-2.0		-0.2	-2.0		-0.2	V
I_{IH}	Input HIGH Current			150			150			150	μA
I_{IL}	Input LOW Current	0.5			0.5			0.5			μA
		D -600 $\bar{D}$			-600			-600			μA

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfm is maintained.

6. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary $\pm 0.3\text{ V}$.

7. Outputs are terminated through a $50\ \Omega$ resistor to $V_{CC} - 2\text{ V}$.

8. V_{IHCMR} min varies 1:1 with V_{EE} , max varies 1:1 with V_{CC} . The V_{IHCMR} range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between V_{ppmin} and 1 V .

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AC CHARACTERISTICS $V_{CC} = 3.3\text{ V}$; $V_{EE} = 0.0\text{ V}$ or $V_{CC} = 0.0\text{ V}$; $V_{EE} = -3.3\text{ V}$ (Note 9)

Symbol	Characteristic	-40 °C			25 °C			85 °C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
$f_{\max}$	Maximum Toggle Frequency					1.0					GHz
t_{PLH} t_{PHL}	Propagation Delay to Output	235		385	255	330	405	285		435	ps
t_{SKEW}	Within-Device Skew (Note 10) Duty Cycle Skew (Note 11)		5 5	20 20		5 5	20 20		5 5	20 20	ps
t_{JITTER}	Random Clock Jitter (RMS)					0.6					ps
V_{PP}	Input Swing (Note 12)	200		1000	200	1000		200	1000		mV
t_r t_f	Output Rise/Fall Times Q (20% - 80%)	120		320	120	220	320	120		320	ps

9. V_{EE} can vary $\pm 0.3\text{ V}$.

10. Within-device skew defined as identical transitions on similar paths through a device.

11. Duty cycle skew is the difference between a TPLH and TPHL propagation delay through a device.

12. $V_{PP}(\min)$ is the minimum input swing for which AC parameters guaranteed. The device will function properly with input swings below 200 mV, however, AC delays may move outside of the specified range. The device has a DC gain of ≈ 40 .

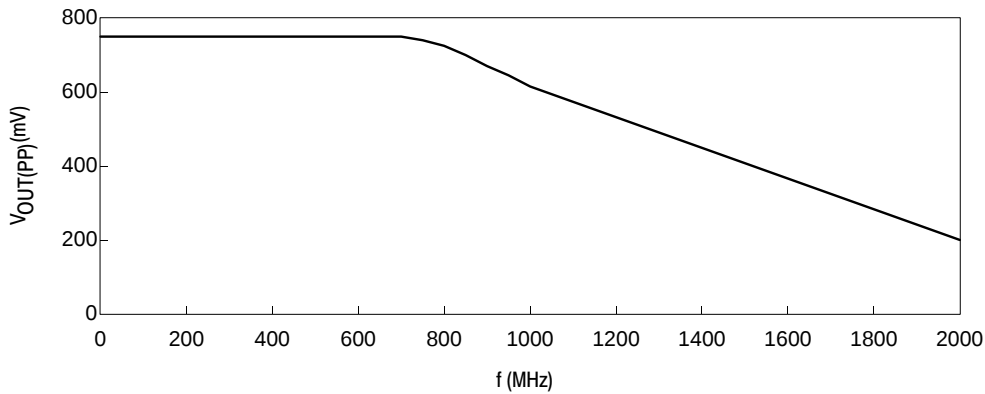


Figure 2. Output Swing versus Frequency

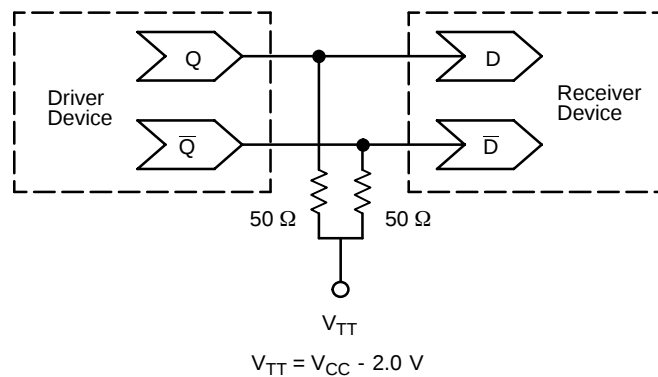


Figure 3. Typical Termination for Output Driver and Device Evaluation
(See Application Note AND8020 - Termination of ECL Logic Devices.)

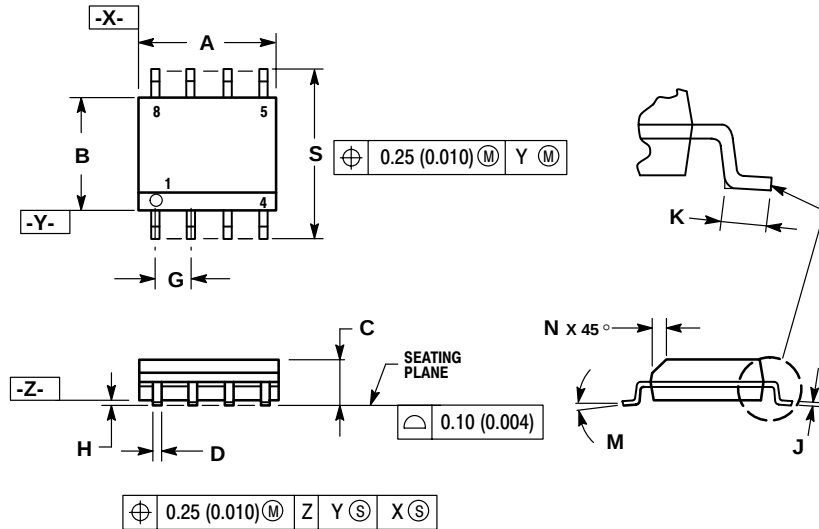
Resource Reference of Application Notes

- AN1404** - ECLinPS Circuit Performance at Non-Standard V_{IH} Levels
- AN1405** - ECL Clock Distribution Techniques
- AN1406** - Designing with PECL (ECL at +5.0 V)
- AN1503** - ECLinPS I/O SPICE Modeling Kit
- AN1504** - Metastability and the ECLinPS Family
- AN1560** - Low Voltage ECLinPS SPICE Modeling Kit
- AN1568** - Interfacing Between LVDS and ECL
- AN1596** - ECLinPS Lite Translator ELT Family SPICE I/O Model Kit
- AN1650** - Using Wire-OR Ties in ECLinPS Designs
- AN1672** - The ECL Translator Guide
- AND8001** - Odd Number Counters Design
- AND8002** - Marking and Date Codes
- AND8020** - Termination of ECL Logic Devices
- AND8090** - AC Characteristics of ECL Devices

MC100LVEL11

PACKAGE DIMENSIONS

SO-8 D SUFFIX PLASTIC SOIC PACKAGE CASE 751-07 ISSUE AA



NOTES:

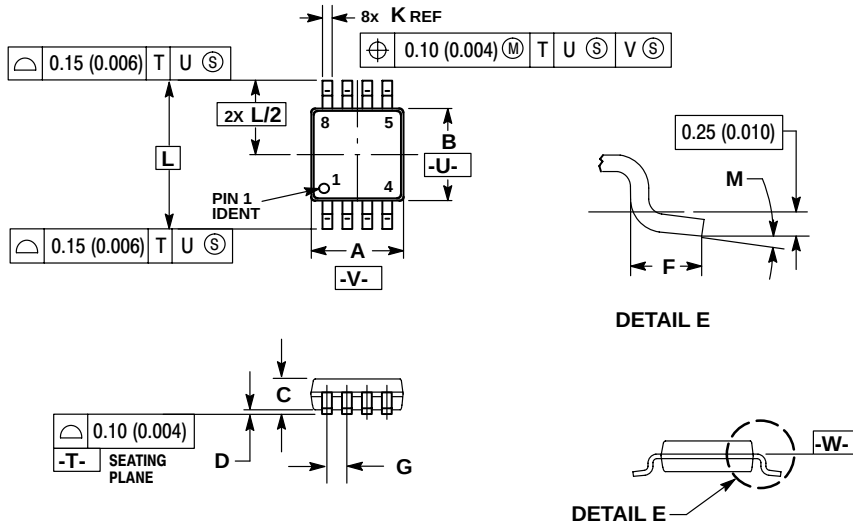
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0°	8°	0°	8°
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

MC100LVEL11

PACKAGE DIMENSIONS

TSSOP-8
DT SUFFIX
PLASTIC TSSOP PACKAGE
CASE 948R-02
ISSUE A



NOTES:

1. DIMENSIONS AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
6. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.90	3.10	0.114	0.122
B	2.90	3.10	0.114	0.122
C	0.80	1.10	0.031	0.043
D	0.05	0.15	0.002	0.006
F	0.40	0.70	0.016	0.028
G	0.65 BSC		0.026 BSC	
K	0.25	0.40	0.010	0.016
L	4.90 BSC		0.193 BSC	
M	0°	6°	0°	6°

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